

mSATA

3IE2-P Series

Customer: _____

Customer

Part

Number: _____

Innodisk

Part

Number: _____

Innodisk

Model Name: _____

Date: _____

| Innodisk Approver | Customer Approver |
|------------------------------|------------------------------|
| | |

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REVISION HISTORY

| Revision | Description | Date |
|-------------|---------------------|-------------|
| Preliminary | First Released | March, 2017 |
| 1.0 | Officially released | April, 2017 |

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1. Product Overview

1.1 Introduction of Innodisk mSATA 3IE2-P

Innodisk mSATA 3IE2-P provides a totally brand new highly cost-effective SSD solution with good performance and longer lifespan. It costs much less than SLC flash but embraces longer life and performance than current MLC flash IC based SSD solution. mSATA 3IE2-P is designed and rigorously tested to ensure industrial-grade reliability. Featuring L² architecture, the life span of the SSD is maximized by an evolved wear leveling algorithm. Furthermore, mSATA 3IE2-P supports TRIM for Windows 7, it can improves performance when deleting files.

mSATA 3IE2-P provides high capacity flash memory within JEDEC MO-300 spec., which electrically compatible with Serial ATA (SATA) standard, and supports SATA III standard (6.0GHz) with high performance.

Better power management which is achieved with DEVSLP is available with the mSATA 3IE2-P. It also features Innodisk iData Guard to protect against unexpected power failures. When the SSD detects power is lost, a special power protection algorithm uses onboard power to save volatile data to non-volatile storage.

1.2 Product View and Models

Innodisk MSATA 3IE2-P is available in follow capacities within MLC flash ICs.

| | |
|-----------------------------------|------------------------------------|
| mSATA 3IE2-P 8GB | mSATA 3IE2-P 64GB |
| mSATA 3IE2-P 16GB | mSATA 3IE2-P 128GB |
| mSATA 3IE2-P 32GB | mSATA 3IE2-P 256GB |



Figure 1: Innodisk mSATA 3IE2-P

1.3 SATA Interface

mSATA 3IE2-P supports SATA III interface, and backward compliant with Serial ATA Gen 1, Gen 2 and Gen 3 specification (Gen 3 supports 1.5Gbps /3.0Gbps/6.0Gbps data rate)..

1.4 Capacity

Innodisk MSATA 3IE2-P provides unformatted 8GB, 16GB, 32GB, 64GB, 128GB, and 256GB capacities within MLC Flash IC.

1.5 MO-300 Form Factor

mSATA 300 has a compact design 29.85 mm (W) x 50.8 mm (L) x 4.85 mm (H) without metal material case, and is easy for installation.

2. Product Specifications

2.1 Capacity and Device Parameters

mSATA 3IE2-P device parameters are shown in Table 1.

Table 1: Device parameters

| Capacity | LBA | Cylinders | Heads | Sectors | User Capacity(MB) |
|----------|-----------|-----------|-------|---------|-------------------|
| 8GB | 13695696 | 13587 | 16 | 63 | 6,687 |
| 16GB | 29323728 | 16383 | 16 | 63 | 14,318 |
| 32GB | 60579792 | 16383 | 16 | 63 | 29,580 |
| 64GB | 121138416 | 16383 | 16 | 63 | 59,150 |
| 128GB | 242255664 | 16383 | 16 | 63 | 118,289 |
| 256GB | 484490160 | 16383 | 16 | 63 | 236,567 |

2.2 Performance

Burst Transfer Rate: 6.0 Gbps

Table 2: Performance

| Capacity | 8GB | 16GB | 32GB | 64GB | 128GB | 256GB |
|-------------------------|-------------|-------------|-------------|-------------|-------------|-------------|
| Sequential Read (max.) | 150 MB/s | 300 MB/s | 560 MB/s | 560 MB/s | 560 MB/s | 560 MB/s |
| Sequential Write (max.) | 60 MB/s | 115 MB/s | 245 MB/s | 310 MB/s | 470 MB/s | 460 MB/s |
| 4KB Random Read (QD32) | 17,000 IOPS | 34,000 IOPS | 51,000 IOPS | 52,000 IOPS | 51,000 IOPS | 50,000 IOPS |
| 4KB Random Write (QD32) | 15,000 IOPS | 30,000 IOPS | 49,000 IOPS | 50,000 IOPS | 50,000 IOPS | 46,000 IOPS |

Note: Based on CrystalDiskMark 5.1.2 with file size 1000MB

2.3 Electrical Specifications

2.3.1 Power Requirement

Table 3: Innodisk MSATA 3IE2-P Power Requirement

| Item | Symbol | Rating | Unit |
|---------------|-----------------|----------------------------|------|
| Input voltage | V _{IN} | +3.3 DC +- 5% 500mA (max.) | V |

2.3.2 Power Consumption

Table 4: Power Consumption

| Mode | Power Consumption |
|-------|-------------------|
| Read | 466 mA (max.) |
| Write | 865 mA (max.) |
| Idle | 91 mA (max.) |

* Target: mSATA 3IE2-P 128GB (Toshiba)

2.4 Environmental Specifications

2.4.1 Temperature Ranges

Table 5: Temperature range for mSATA 3IE2-P

| Temperature | Range |
|-------------|----------------------------------|
| Operating | Standard Grade: 0°C to +70°C |
| | Industrial Grade: -40°C to +85°C |
| Storage | -55°C to +95°C |

2.4.2 Humidity

Relative Humidity: 10-95%, non-condensing

2.4.3 Shock and Vibration

Table 6: Shock/Vibration Testing for mSATA 3IE2-P

| Reliability | Test Conditions | Reference Standards |
|------------------|---------------------------------|---------------------|
| Vibration | 7 Hz to 2K Hz, 20G, 3 axes | IEC 68-2-6 |
| Mechanical Shock | Duration: 0.5ms, 1500 G, 3 axes | IEC 68-2-27 |

2.4.4 Mean Time between Failures (MTBF)

Table 7 summarizes the MTBF prediction results for various mSATA 3IE2-P configurations. The analysis was performed using a RAM Commander™ failure rate prediction.

- **Failure Rate:** The total number of failures within an item population, divided by the total number of life units expended by that population, during a particular measurement interval under stated condition.
- **Mean Time between Failures (MTBF):** A basic measure of reliability for repairable items:

The mean number of life units during which all parts of the item perform within their specified limits, during a particular measurement interval under stated conditions.

Table 7: mSATA 3IE2-P MTBF

| Product | Condition | MTBF (Hours) |
|-----------------------|---------------------------|--------------|
| Innodisk mSATA 3IE2-P | Telcordia SR-332 GB, 25°C | >3,000,000 |

2.5 CE and FCC Compatibility

mSATA 3IE2-P conforms to CE and FCC requirements.

2.6 RoHS Compliance

mSATA 3IE2-P is fully compliant with RoHS directive.

2.7 Reliability

| Parameter | | Value |
|----------------------------|---------------------|-----------------------|
| Read Cycles | | Unlimited Read Cycles |
| Flash Endurance | | 20,000 P/E cycles |
| Wear-Leveling Algorithm | | Support |
| Bad Blocks Management | | Support |
| Error Correct Code | | Support |
| iData Guard | | Support |
| Thermal Sensor | | Support |
| TBW* (Total Bytes Written) | | Unit: TB |
| Capacity | Sequential workload | Client workload |
| 08GB | 142 | 78.1 |
| 16GB | 284.1 | 156.3 |
| 32GB | 568.2 | 312.5 |
| 64GB | 1136 | 625 |
| 128GB | 2273 | 1250 |
| 256GB | 4545 | 2500 |

* Note:

1. Sequential: Mainly sequential write, tested by Vdbench.
2. Client: Follow JESD218 Test method and JESD219A Workload, tested by ULINK. (The capacity lower than 64GB client workload is not specified in JEDEC219A, the values are estimated.)
3. Based on out-of-box performance.

2.8 Transfer Mode

MSATA 3IE2-P support following transfer mode:

Serial ATA III 6.0Gbps

Serial ATA II 3.0Gbps

Serial ATA I 1.5Gbps

2.9 Pin Assignment

Innodisk mSATA 3IE2-P uses a standard SATA pin-out. See Table 8 for mSATA 3IE2-P pin assignment.

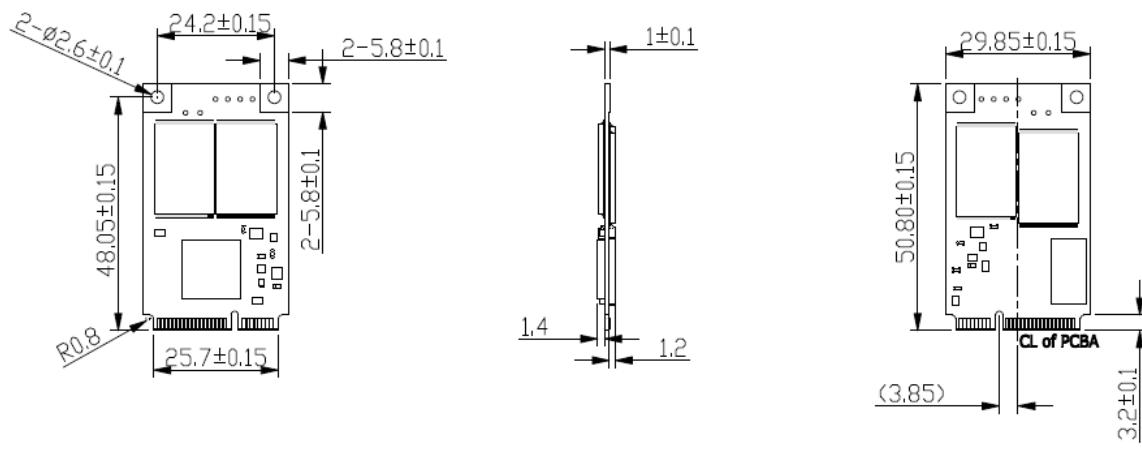
Table 8: Innodisk mSATA 3IE2-P Pin Assignment

| Signal Name | Pin # | Pin # | Signal Name |
|-------------|-------|-------|-------------|
| GND | 51 | 52 | +3.3V |
| DAS | 49 | 50 | GND |
| NC | 47 | 48 | NC |
| NC | 45 | 46 | NC |
| NC | 43 | 44 | DEVSLP |
| +3.3V | 41 | 42 | NC |
| +3.3V | 39 | 40 | GND |
| GND | 37 | 38 | NC |
| GND | 35 | 36 | NC |
| RX+ | 33 | 34 | GND |
| RX- | 31 | 32 | NC |
| GND | 29 | 30 | NC |
| GND | 27 | 28 | NC |
| TX- | 25 | 26 | GND |
| TX+ | 23 | 24 | +3.3V |
| GND | 21 | 22 | NC |
| NC | 19 | 20 | NC |
| NC | 17 | 18 | GND |
| | | | |
| GND | 15 | 16 | NC |
| NC | 13 | 14 | NC |
| NC | 11 | 12 | NC |

| | | | |
|-----|---|----|-------|
| GND | 9 | 10 | NC |
| NC | 7 | 8 | NC |
| NC | 5 | 6 | NC |
| NC | 3 | 4 | GND |
| NC | 1 | 2 | +3.3V |

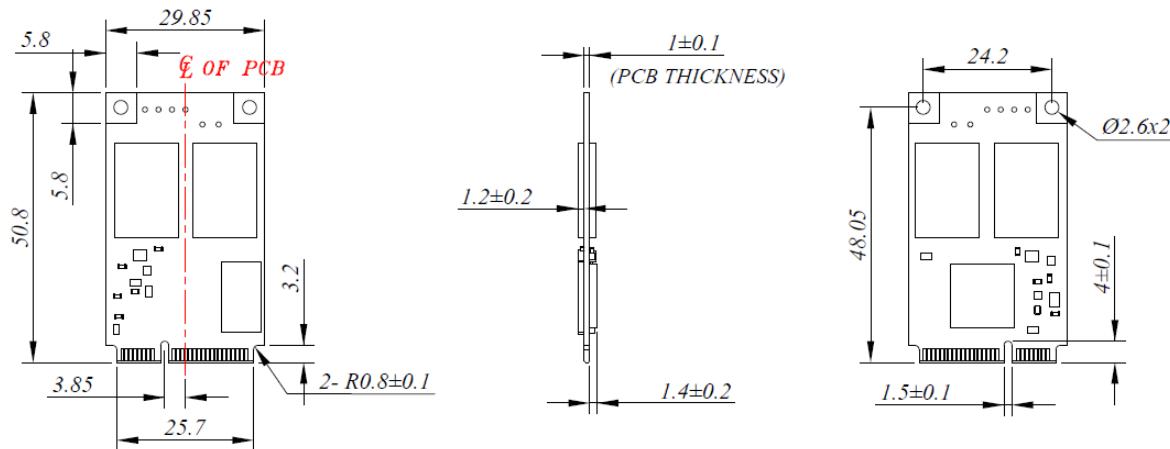
2.10 Mechanical Dimensions

TSOP



TOLERANCE: ±0.20 mm
UNIT: mm

BGA 256GB



TOLERANCE: ±0.15mm
UNIT: mm

2.11 Assembly Weight

An Innodisk mSATA 3IE2-P within MLC flash ICs, 32GB's weight is 10 grams approx.

2.12 Seek Time

Innodisk mSATA 3IE2-P is not a magnetic rotating design. There is no seek or rotational latency required.

2.13 NAND Flash Memory

Innodisk mSATA 3IE2-P uses Multi Level Cell (MLC) NAND flash memory, which is non-volatile, high reliability and high speed memory storage. Each cell stores 2 bits or holds four states per cell. Read or Write data to flash memory for SSD is control by microprocessor.

3. Theory of Operation

3.1 Overview

Figure 2 shows the operation of Innodisk mSATA 3IE2-P from the system level, including the major hardware blocks.

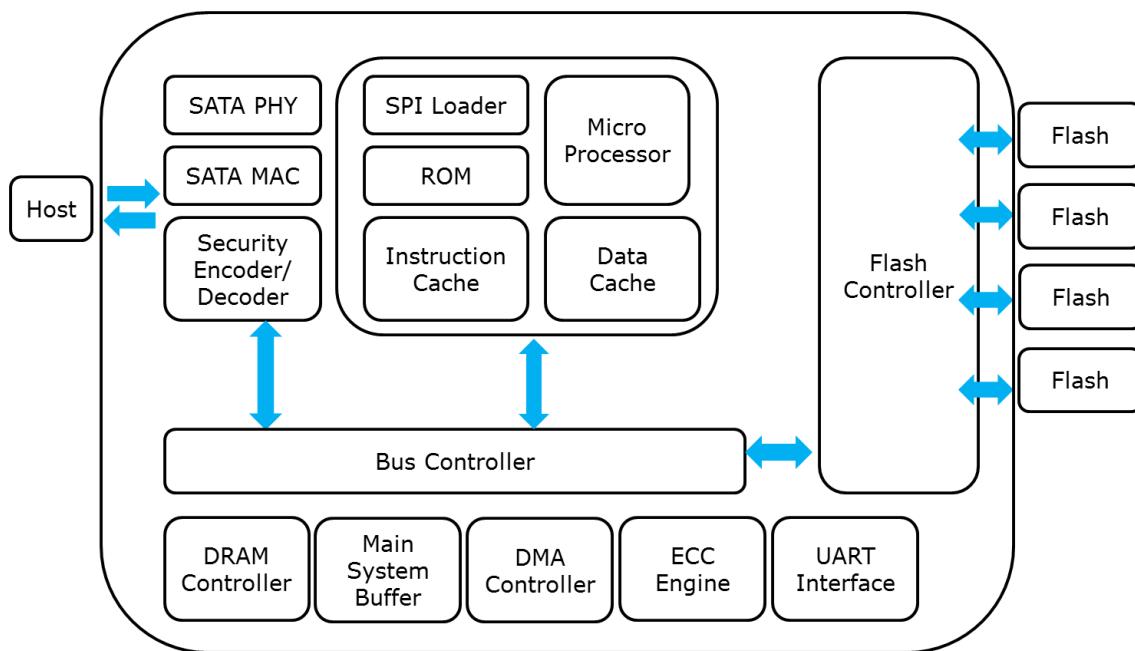


Figure 2: Innodisk mSATA 3IE2-P Block Diagram

Innodisk 2 mSATA 3IE2-P integrates a SATA III controller and NAND flash memories. Communication with the host occurs through the host interface, using the standard ATA protocol. Communication with the flash device(s) occurs through the flash interface.

3.2 SATA III Controller

Innodisk mSATA 3IE2-P is designed with ID 201, a SATA III 6.0Gbps (Gen. 3) controller, which supports external DDR3 DRAM. The Serial ATA physical, link and transport layers are compliant with Serial ATA Gen 1, Gen 2 and Gen 3 specification (Gen 3 supports 1.5Gbps/3.0Gbps/6.0Gbps data rate). The controller has 4 channels for flash interface.

3.3 Error Detection and Correction

Highly sophisticated Error Correction Code algorithms are implemented. The ECC unit consists of the Parity Unit (parity-byte generation) and the Syndrome Unit (syndrome-byte computation). This unit implements an algorithm that can correct 66 bits per 1024 bytes in an ECC block. Code-byte generation during write operations, as well as error detection during read operation, is implemented on the fly without any speed penalties.

3.4 Wear-Leveling

Flash memory can be erased within a limited number of times. This number is called the **erase cycle limit** or **write endurance limit** and is defined by the flash array vendor. The erase cycle limit applies to each individual erase block in the flash device.

Innodisk mSATA 3IE2-P uses a static wear-leveling algorithm to ensure that consecutive writes of a specific sector are not written physically to the same page/block in the flash. This spreads flash media usage evenly across all pages, thereby extending flash lifetime.

3.5 Bad Blocks Management

Bad Blocks are blocks that contain one or more invalid bits whose reliability are not guaranteed. The Bad Blocks may be presented while the SSD is shipped, or may develop during the life time of the SSD. When the Bad Blocks is detected, it will be flagged, and not be used anymore. The SSD implement Bad Blocks management, Bad Blocks replacement, Error Correct Code to avoid data error occurred. The functions will be enabled automatically to transfer data from Bad Blocks to spare blocks, and correct error bit.

3.6 iData Guard

Innodisk's iData Guard is a comprehensive data protection mechanism that functions before and after a sudden power outage to SSD. Low-power detection terminates data writing before an abnormal power-off, while table-remapping after power-on deletes corrupt data and maintains data integrity. Innodisk's iData Guard provides effective power cycling management, preventing data stored in flash from degrading with use.

3.7 Garbage Collection/TRIM

Garbage collection and TRIM technology is used to maintain data consistency and perform continual data cleansing on SSDs. It runs as a background process, freeing up valuable controller resources while sorting good data into available blocks, and deleting bad blocks. It also significantly reduces write operations to the drive, thereby increasing the SSD's speed and lifespan.

4. Installation Requirements

4.1 mSATA 3IE2-P Pin Directions

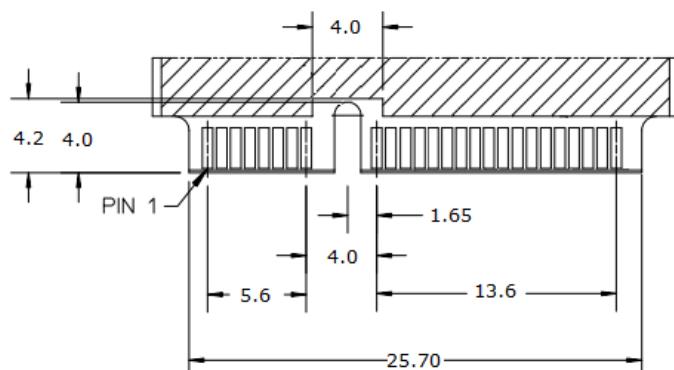


Figure 3: Signal Segment and Power Segment

4.2 Electrical Connections for mSATA 3IE2-P

A Serial ATA device may be either directly connected to a host or connected to a host through a cable. For connection via cable, the cable should be no longer than 1meter. The SATA interface has a separate connector for the power supply. Please refer to the pin description for further details.

4.3 Device Drive

No additional device drives are required. Innodisk mSATA 3IE2-P can be configured as a boot device.

5. SMART Feature Set

Innodisk 3IE2-P support the SMART command set and defines some vendor-specific data to report SMART attributes of SSD.

| Value | Command |
|-------|----------------------------|
| D0h | Read Data |
| D1h | Read Attribute Threshold |
| D2h | Enable/Disable Autosave |
| D3h | Save Attribute Values |
| D4h | Execute OFF-LINE Immediate |
| D5h | Read Log |
| D6h | Return Status |
| D8h | Enable SMART Operations |
| D9h | Disable SMART Operations |
| DAh | Return Status |

5.1 SMART Attributes

Innodisk's 3IE2-P series SMART data attributes are listed in following table.

| Attribute ID (hex) | Raw Attribute Value | | | | | | | Attribute Name |
|--------------------|---------------------|-----|----|-----|----|----|----|--------------------------|
| 1 (01h) | MSB | 00 | 00 | 00 | 00 | 00 | 00 | Raw Read Error Rate |
| 5 (05h) | LSB | MSB | 00 | 00 | 00 | 00 | 00 | Reallocated Sector Count |
| 9 (09h) | LSB | | | MSB | 00 | 00 | 00 | Power-on Hours |
| 12 (0Ch) | LSB | | | MSB | 00 | 00 | 00 | Power Cycle Count |

| | | | | | | | | |
|-----------|-----|-----|----|-----|----|----|-----|---|
| 160 (A0h) | LSB | | | MSB | 00 | 00 | 00 | Uncorrectable sector count when read/write |
| 161 (A1h) | LSB | MSB | 00 | 00 | 00 | 00 | 00 | Number of valid spare block |
| 163 (A3h) | LSB | MSB | 00 | 00 | 00 | 00 | 00 | Number of initial invalid block |
| 164 (A4h) | LSB | MSB | 00 | 00 | 00 | 00 | 00 | Total erase count |
| 165 (A5h) | LSB | | | MSB | 00 | 00 | 00 | Maxumum erase count |
| 166 (A6h) | LSB | | | MSB | 00 | 00 | 00 | Minimum erase count |
| 167 (A7h) | LSB | | | MSB | 00 | 00 | 00 | Average erase count |
| 168 (A8h) | LSB | | | MSB | 00 | 00 | 00 | Max erase count of spec |
| 169 (A9h) | LSB | | | MSB | 00 | 00 | 00 | Reman Life (percentage) |
| 175 (AFh) | LSB | | | MSB | 00 | 00 | 00 | Program fail count in worst die |
| 176 (B0h) | LSB | | | MSB | 00 | 00 | 00 | Erase fail count in worst die |
| 177 (B1h) | LSB | | | MSB | 00 | 00 | 00 | Total wear level count |
| 178 (B2h) | LSB | MSB | 00 | 00 | 00 | 00 | 00 | Runtime invalid block count |
| 181 (B5h) | LSB | | | MSB | 00 | 00 | 00 | Total program fail count |
| 182 (B6h) | LSB | MSB | 00 | 00 | 00 | 00 | 00 | Total erase fail count |
| 187 (BBh) | LSB | | | MSB | 00 | 00 | 00 | Uncorrectable error count |
| 192 (C0h) | LSB | MSB | 00 | 00 | 00 | 00 | 00 | Power-Off Retract Count |
| 194 (C2h) | MSB | 00 | 00 | 00 | 00 | 00 | 00 | Controlled temperature |
| 195 (C3h) | LSB | | | MSB | 00 | 00 | 00 | Hardware ECC recovered |
| 196 (C4h) | LSB | | | MSB | 00 | 00 | 00 | Reallocation event count |
| 198 (C6h) | LSB | | | MSB | 00 | 00 | 00 | Uncorrectable error count off-line |
| 199 (C7h) | LSB | MSB | 00 | 00 | 00 | 00 | 00 | UltraDMA CRC error count |
| 225 (E1h) | LSB | | | | | | MSB | Total LBAs written (each write unit = 32MB) |
| 232 (E8h) | LSB | MSB | 00 | 00 | 00 | 00 | 00 | Available reserved space |
| 241 (F1h) | LSB | | | | | | MSB | Total LBAs written (each write unit = 32MB) |
| 242 (F2h) | LSB | | | | | | MSB | Total LBAs read (each write unit = 32MB) |

6. Part Number Rule

| CODE | 1 | 2 | 3 | 4 | 5 | 6 | 7 | 8 | 9 | 10 | 11 | 12 | 13 | 14 | 15 | 16 | 17 | 18 | 19 | 20 |
|-------------|------|-----------------|---|----------|----------|---------------|--------------------|---------------------|-----|-------|----|--------------------|----|----|----|----|----|----|----|----|
| | D | H | M | S | R | - | 3 | 2 | G | D | 8 | 1 | B | C | 1 | D | C | - | X | X |
| Description | Disk | mSATA 3IE2-P | | Capacity | Category | Flash Mode | Operation Temp. | Internal Control | CH. | Flash | - | Customized Code | | | | | | | | |

Definition

| Code 1 st (Disk) | Code 13 th (Flash Mode) |
|---|---|
| D : Disk | B:15nm Synchronous flash |
| Code 2nd ~ 5th (Form Factor) | Code 14th (Operation Temperature) |
| HMSR: mSATA 3IE2-P | C: Standard Grade (0°C ~ +70°C) |
| Code 7th ~9th (Capacity) | W: Industrial Grade (-40°C ~ +85°C) |
| 08G: 8GB | Code 15th (Internal control) |
| 16G: 16GB | 1~9 : TSOP PCB version |
| 32G: 32GB | A~Z: BGA PCB version |
| 64G: 64GB | Code 16th (Channel of data transfer) |
| A28: 128GB | D: Dual Channels |
| B56: 256GB | Q: Quad Channels |
| Code 10th ~12th (Series) | Code 17th (Flash Type) |
| D81: ID201 | C: Toshiba MLC |
| | Code 19th~20th (Customized Code) |
| | |

Appendix



**宜鼎國際股份有限公司
Innodisk Corporation**

Tel:(02)7703-3000 Fax:(02) 7703-3555 Internet: <http://www.innodisk.com/>

RoHS 自我宣告書(RoHS Declaration of Conformity)

Manufacturer Product: All Innodisk EM Flash and Dram products

- 一、 宜鼎國際股份有限公司（以下稱本公司）特此保證售予貴公司之所有產品，皆符合歐盟2011/65/EU 關於 RoHS 之規範要求。
 Innodisk Corporation declares that all products sold to the company, are complied with European Union RoHS Directive (2011/65/EU) requirement
- 二、 本公司同意因本保證書或與本保證書相關事宜有所爭議時，雙方宜友好協商，達成協議。
 Innodisk Corporation agrees that both parties shall settle any dispute arising from or in connection with this Declaration of Conformity by friendly negotiations.

| Name of hazardous substance | Limited of RoHS ppm (mg/kg) |
|--------------------------------|-----------------------------|
| Cd | < 100 ppm |
| Pb | < 1000 ppm |
| Hg | < 1000 ppm |
| Chromium VI (Cr+6) | < 1000 ppm |
| Polybromodiphenyl ether (PBDE) | < 1000 ppm |
| Polybrominated Biphenyls (PBB) | < 1000 ppm |

立 保 證 書 人 (Guarantor)

Company name 公司名稱：Innodisk Corporation 宜鼎國際股份有限公司

Company Representative 公司代表人：Richard Lee 李鐘亮

Company Representative Title 公司代表人職稱：CEO 執行長

Date 日期：2014 / 07 / 29



Verification of Compliance

Product Name : mSATA
Model Number : mSATA 3\$*#-&
 \$:Flash type: (S:SLC,I:iSLC,M:MLC)
 *: Product line: (E:Embedded, G: EverGreen)
 #:controller:
 (empty:606/607/667/670, 2: SMI 2246XT/ 2246EN, 3:608/609)
 &: Product feature: (P: with DRAM, empty: without DRAM)
Applicant : Innodisk Corporation
Address : 5F.No.237, Sec. 1, Datong Rd., Xizhi Dist., New Taipei City 221,
 Taiwan (R.O.C.)
Report Number : S3F-U070-1307-314
Issue Date : December 10, 2014

Applicable Standards : FCC Part 15, Subpart B Class B ITE
 ANSI C63.4:2009
 Industry Canada ICES-003 Issue 5
 CAN/CSA-CISPR 22-10 Class B ITE

One sample of the designated product has been tested in our laboratory and found to be in compliance with the FCC rules cited above.



NVLAP LAB CODE 200575-0

TAF 0905

FCC CAB Code TW1053

IC Code 4699A

VCCI Accep. No. R-1527, C-1609, T-1441, G-10,
C-4400, T-1334, G-614



Central Research Technology Co.

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11, Lane 41, Fushuen St., Jungshan Chiu,
Taipei, Taiwan, 104, R.O.C.
Tel : 886-2-25984568
Fax: 886-2-25984546

A handwritten signature in black ink, appearing to read "Tsun-Yu Shih".

(Tsun-Yu Shih/ General Manager)

Date: December 10, 2014

Verification of Compliance

Product Name : mSATA
Model Number : mSATA 3\$*#-&
 \$:Flash type: (S:SLC,I:ISLC,M:MLC)
 *: Product line: (E:Embedded, G: EverGreen)
 #:controller:
 (empty:606/607/667/670, 2: SMI 2246XT/ 2246EN, 3:608/609)
 &: Product feature: (P: with DRAM, empty: without DRAM)
Applicant : Innodisk Corporation
Address : 5F.No.237, Sec. 1, Datong Rd., Xizhi Dist., New Taipei City 221,
 Taiwan (R.O.C.)
Report Number : S3O22-U070-1307-314
Issue Date : December 10, 2014
Applicable Standards : EN 55022:2010+AC:2011 Class B ITE
 AS/NZS CISPR22:2009+A1:2010 Class B ITE
 EN 55024:2010
 EN 61000-4-2:2009
 EN 61000-4-3:2006+A1:2008+A2:2010
 EN 61000-4-4:2004+A1:2010

Based on the EMC Directive 2004/108/EC and the specifications of the customer, one sample of the designated product has been tested in our laboratory and found to be in compliance with the EMC standards cited above.



TAF 0905

FCC CAB Code TW1053

NVLAP Lab Code 200575-0

IC Code 4699A

VCCI Accep. No. R-1527, C-1609, T-1441, G-10,
C-4400, T-1334, G-614

Central Research Technology Co.

EMC Test Laboratory

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(Tsun-Yu Shih/ General Manager)

Date: December 10, 2014



宜鼎國際股份有限公司
Innodisk Corporation

Tel:(02)7703-3000 Fax:(02) 7703-3555 Internet: <http://www.innodisk.com/>

REACH Declaration of Conformity

Manufacturer Product: All Innodisk EM Flash and Dram products

1. 宜鼎國際股份有限公司（以下稱本公司）特此保證此售予貴公司之產品，皆符合歐盟化學品法案(Registration , Evaluation and Authorization of Chemicals ; REACH)之規定 (<http://www.echa.europa.eu/de/candidate-list-table> **last updated: 16/06/2014**)。所提供之產品包含：(1) 產品或產品所使用到的所有原物料；(2)包裝材料；(3)設計、生產及重工過程中所使用到的所有原物料。

We Innodisk Corporation hereby declare that our products are in compliance with the requirements according to the REACH Regulation (<http://www.echa.europa.eu/de/candidate-list-table> **last updated: 16/06/2014**). Products include : 1) Product and raw material used by the product ; 2) Packaging material ; 3) Raw material used in the process of design, production and rework

2. 本公司同意因本保證書或與本保證書相關事宜有所爭議時，雙方宜友好協商，達成協議。

InnoDisk Corporation agrees that both parties shall settle any dispute arising from or in connection with this Declaration of Conformity by friendly negotiations.

立 保 證 書 人 (Guarantor)

Company name 公司名稱：InnoDisk Corporation 宜鼎國際股份有限公司

Company Representative 公司代表人：Richard Lee 李鐘亮

Company Representative Title 公司代表人職稱：CEO 執行長

Date 日期：2014 / 07 / 29



(Company Stamp/公司六小章)